

## Features

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

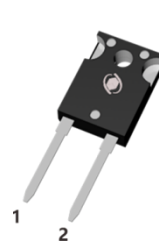
$V_{RRM}$	1200V
$I_F (T_c = 150.5^\circ\text{C})$	30A
$Q_c$	160nC

## Benefits

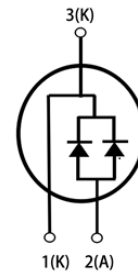
- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

## Applications

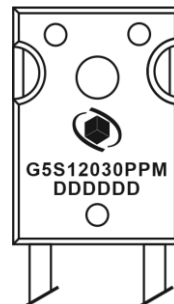
- SMPS, PFC
- Solar application, UPS, EV/HEV
- Motor drives, Wind turbine, Rail traction



TO-247AC



Inner Circuit



G = GPT  
5 = Gen5  
S = SiC Schottky Diode  
120 = Voltage Rating 1200V  
30 = Current Rating 30A  
PPM = TO-247AC  
DDDDDD = Traceable Code





**Maximum Ratings** (at  $T_j = 25^\circ\text{C}$ , unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	1200	V
Surge Peak Reverse Voltage	$V_{RSM}$	1200	V
Continuous Forward Current $T_c = 25^\circ\text{C}$ $T_c = 135^\circ\text{C}$ $T_c = 150.5^\circ\text{C}$	$I_F$	85.2 40.4 30	A
Repetitive Peak Forward Surge Current $T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ , Half Sine Pulse	$I_{FRM}$	150	A
Non-Repetitive Forward Surge Current $T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ , Half Sine Pulse	$I_{FSM}$	350	A
$i^2t$ Value $T_c = 25^\circ\text{C}$ , $t_p = 10\text{ms}$ , Half Sine Pulse	$\int i^2 dt$	612.5	$\text{A}^2\text{s}$
Power Dissipation $T_c = 25^\circ\text{C}$ $T_c = 110^\circ\text{C}$	$P_{tot}$	362 156	W
Operating Junction Range	$T_j$	-55 to +175	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +175	$^\circ\text{C}$
Mounting Torque, M3 Screw	M	1	Nm

**Electrical Characteristics** (at  $T_J = 25^\circ\text{C}$ , unless otherwise specified)

Parameter	Symbol	Test Condition	Value			Unit
			min.	typ.	max.	
DC Blocking Voltage	$V_{DC}$		1200	-	-	V
Forward Voltage	$V_F$	$I_F = 30\text{A}$				
		$T_J = 25^\circ\text{C}$	-	1.4	1.7	V
		$T_J = 175^\circ\text{C}$	-	1.95	2.5	
Reverse Current	$I_R$	$V_R = 1200\text{V}$				
		$T_J = 25^\circ\text{C}$	-	11	100	$\mu\text{A}$
		$T_J = 175^\circ\text{C}$	-	64	200	
Total Capacitance	C	$f = 1\text{MHz}$				
		$V_R = 0\text{V}$	-	2492	-	$\text{pF}$
		$V_R = 400\text{V}$	-	149.2	-	
		$V_R = 800\text{V}$	-	126	-	
Total Capacitive Charge	$Q_C$	$V_R = 800\text{V}$ $T_J = 25^\circ\text{C}$	-	160	-	nC
Capacitance Stored Energy	$E_C$	$V_R = 800\text{V}$	-	82	-	$\mu\text{J}$

**Thermal Characteristics**

Parameter	Symbol	Test Condition	Value			Unit
			min.	typ.	max.	
Thermal Resistance, junction-case	$R_{th(j-c)}$		-	0.415	-	$^\circ\text{C/W}$



### Typical Characteristics Curves

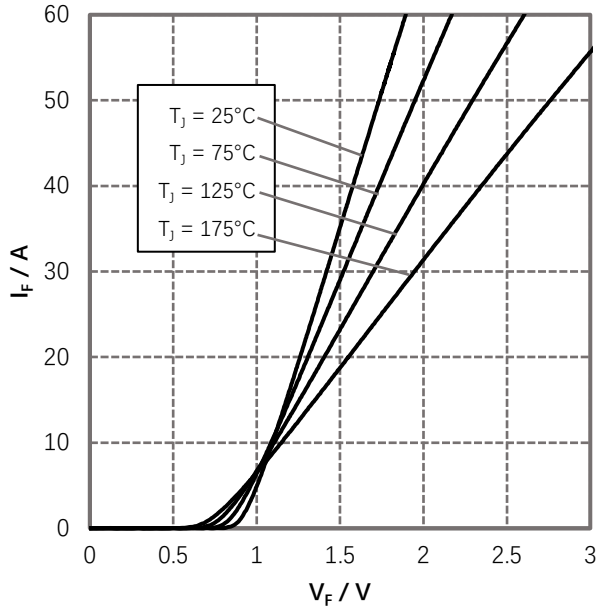


Figure 1. Forward Characteristics

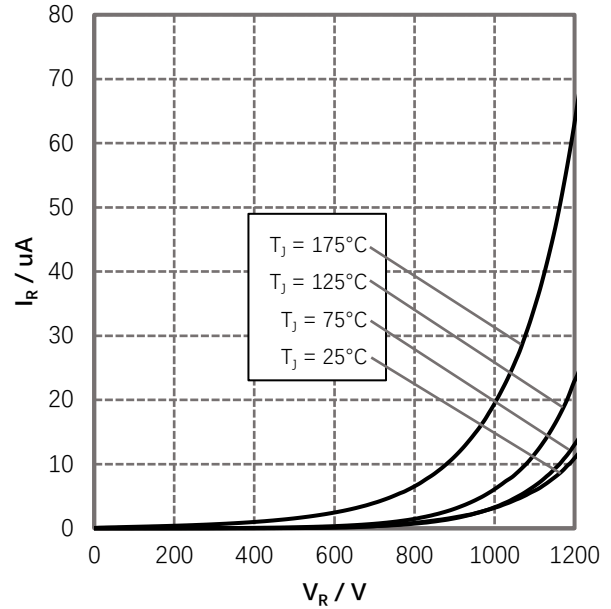


Figure 2. Reverse Characteristics

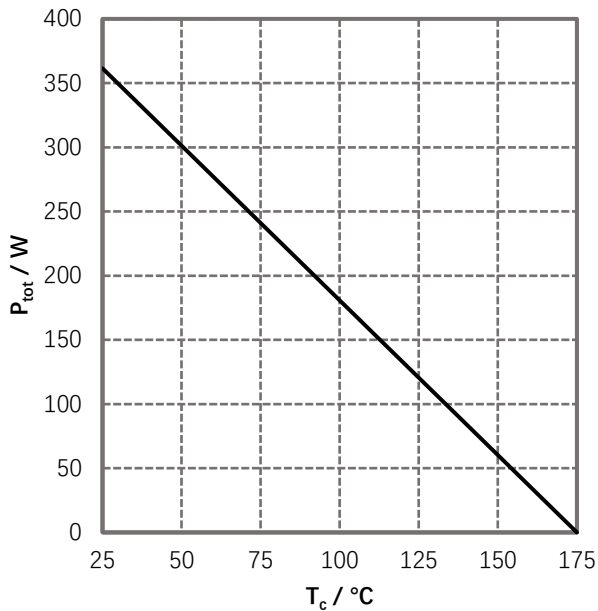


Figure 3. Power Derating

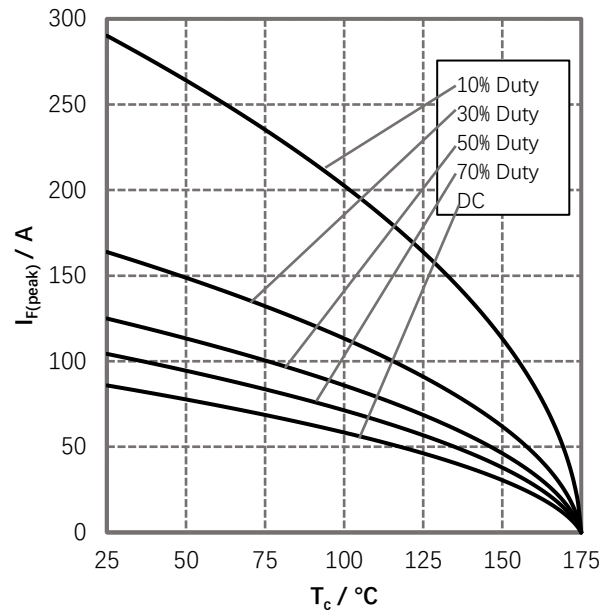


Figure 4. Current Derating



### Typical Characteristics Curves

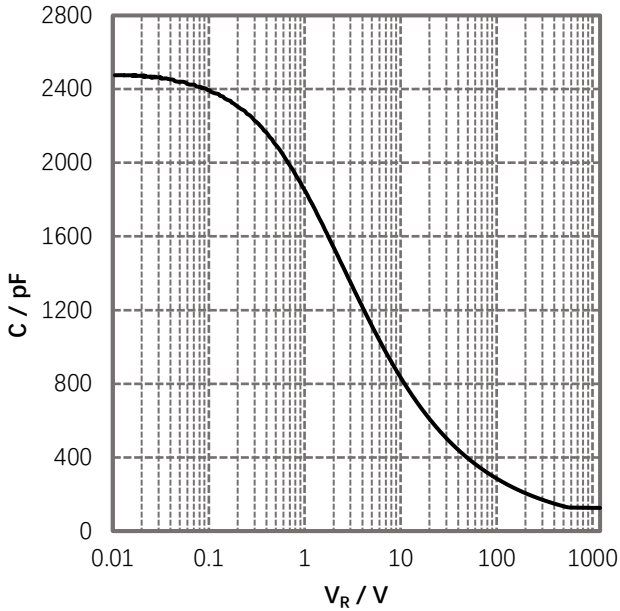


Figure 5. Capacitance vs. Reverse Voltage

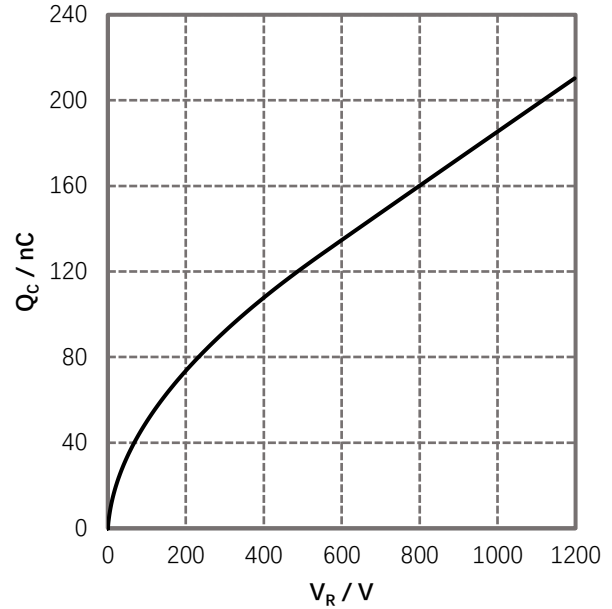


Figure 6. Reverse Charge vs. Reverse Voltage

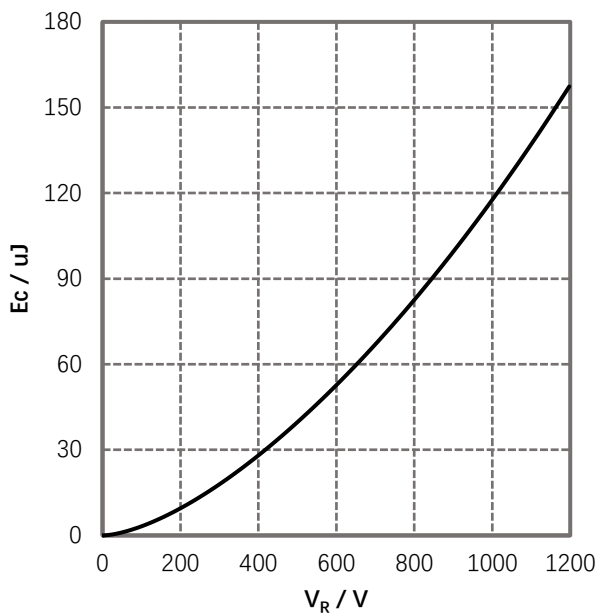


Figure 7. Capacitance Stored Energy

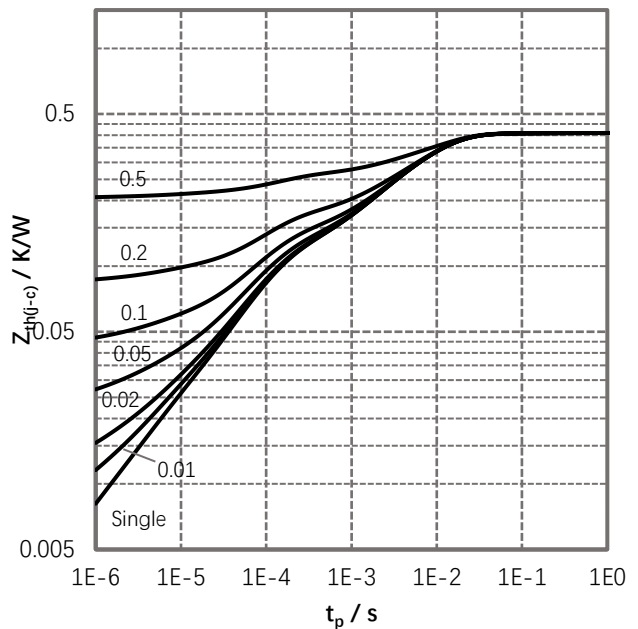
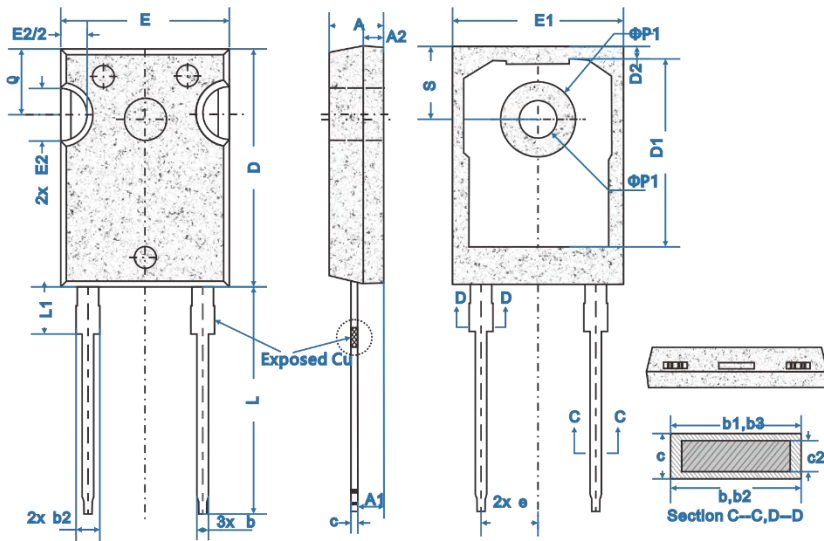


Figure 8. Transient Thermal Impedance



**Package Dimensions**



Unit: mm

Symbol	Dimensions			Notes
	Min	NOM.	Max.	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.34	6
b3	1.91	2.00	2.34	
c	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44 BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ΦP	3.58	3.61	3.65	7
ΦP1	7.19 Ref.			
Q	5.39	5.79	6.2	
S	6.04	6.17	6.3	

**Note:**

1. Package reference: JEDEC TO247, variation AD.
2. All Dimensions are in mm.
3. Slot required, Notch may be rounded.
4. Dimension D & E do not include Mold Flash. Mold Flash shall not exceed 0.127 pre side. These dimension are measured at the outermost extreme of the Plastic Body.
5. Thermal Pad contour optional within dimension D1 & E1.
6. Lead finish uncontrolled in L1.
7. ΦP to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 3.19mm.
8. Dimension "b2" and "b4" does not include Dambar Protrusion. Allowable Dambar protrusion shall be 0.10mm total in excess of "b2" and "b4" dimension at maximum material condition.

**Ordering Information**

Part Number	Marking	Package	Packaging Mode
G5S12030PPM	G5S12030PPM	TO-247AC	30pcs/Tube

## Notes

- Global Power Technology reserves the right to change or modify any of the products and their inherent physical and technical specifications without prior notice.
- The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics.

## Related Links

- Global Power Technology Website: <http://www.globalpowertech.cn/>
- GPT online store is now open! you can place an order directly online, buy it easily, and send it directly from the factory! For more detailed product, price information and coupon activities, please log in to GPT online store: <http://sc.globalpowertech.cn/>

